

TC7SL04F, TC7SL04FU

INVERTER

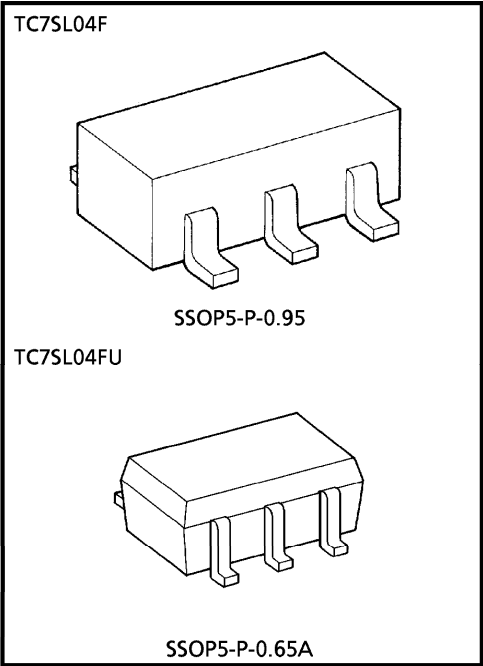
The TC7SL04 is a low voltage operative C²MOS INVERTER fabricated with silicon gate C²MOS technology. Operating voltage (V_{CC (opr)}) is 1~3V equivalent to 1pc or 2pcs of dry cell battery and it achives low power dissipation. The internal circuit is composed of 3 stages including buffer output, which enables high noise immunity and stable output. The input is equipped with protection circuits against static discharge or transient excess voltage.

FEATURES

- High Speed t_{pd} = 10ns (Typ.)
at V_{CC} = 3V
- Low Power Dissipation I_{CC} = 1μA (Max.)
at Ta = 25°C
- High Noise Immunity V_{NIH} = V_{NIL}
= 28% V_{CC} (Min.)
- Symmetrical Output Impedance |I_{OH}| = I_{OL} = 1mA
- Balanced Propagation Delay Time ... t_{pLH} ≒ t_{pHL}
- Low Voltage Operating V_{CC (opr)} = 1~3.6V

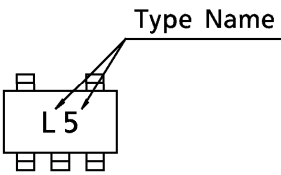
MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V _{CC}	- 0.5~5	V
DC Input Voltage	V _{IN}	- 0.5~V _{CC} + 0.5	V
DC Output Voltage	V _{OUT}	- 0.5~V _{CC} + 0.5	V
Input Diode Current	I _{IK}	± 20	mA
Output Diode Current	I _{OK}	± 20	mA
DC Output Current	I _{OUT}	± 12.5	mA
DC V _{CC} / Ground Current	I _{CC}	± 25	mA
Power Dissipation	P _D	200	mW
Storage Temperature	T _{stg}	- 65~150	°C
Lead Temperature (10s)	T _L	260	°C



Weight SSOP5-P-0.95 : 0.016g (Typ.)
SSOP5-P-0.65A : 0.006g (Typ.)

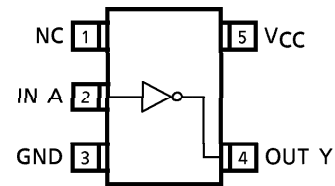
MARKING



LOGIC DIAGRAM



PIN CONNECTION (TOP VIEW)



RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	1~3.6	V
Input Voltage	V_{IN}	0~ V_{CC}	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C
Input Rise and Fall Time	t_r, t_f	0~1000 ($V_{CC} = 1.0V$)	ns
		0~500 ($V_{CC} = 1.5V$)	
		0~400 ($V_{CC} = 3.0V$)	

DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	V_{CC}	$T_a = 25^{\circ}C$			$T_a = -40 \sim 85^{\circ}C$		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
High-Level Input Voltage	V_{IH}	—	—	1.0 1.5 3.0	0.75 1.05 2.10	— — —	— — —	0.75 1.05 2.10	— — —	V
Low-Level Input Voltage	V_{IL}	—	—	1.0 1.5 3.0	— — —	— — —	0.25 0.45 0.90	— — —	0.25 0.45 0.90	V
High-Level Output Voltage	V_{OH}	—	$V_{IN} = V_{IL}$	$I_{OH} = -20\mu A$	1.0 1.5 3.0	0.9 1.4 2.9	1.0 1.5 3.0	— — —	0.9 1.4 2.9	V
				$I_{OH} = -1mA$	1.5 3.0	1.07 2.61	1.23 2.68	— —	0.99 2.55	
				$I_{OH} = -2.6mA$	3.0	2.61	2.68	—	2.55	
Low-Level Output Voltage	V_{OL}	—	$V_{IN} = V_{IH}$	$I_{OL} = 20\mu A$	1.0 1.5 3.0	— — —	0.0 0.0 0.0	0.1 0.1 0.1	— — —	V
				$I_{OL} = 1mA$	1.5 3.0	— —	0.23 0.23	0.31 0.31	— —	
				$I_{OL} = 2.6mA$	3.0	—	0.23	0.31	—	
Input Leakage Current	I_{IN}	—	$V_{IN} = V_{CC}$ or GND	3.6	—	—	± 0.1	—	± 1.0	μA
Quiescent Supply Current	I_{CC}	—	$V_{IN} = V_{CC}$ or GND	3.6	—	—	1.0	—	10.0	

AC ELECTRICAL CHARACTERISTICS (C_L = 15pF, Input t_r = t_f = 6ns, V_{CC} = 3.3 ± 0.3V)

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	Ta = 25°C			UNIT
				MIN.	TYP.	MAX.	
Output Transition Time	t _{TLH} t _{THL}	—	—	—	5.0	9.0	ns
Propagation Delay Time	t _{PLH} t _{PHL}	—	—	—	7.5	13.0	ns

AC ELECTRICAL CHARACTERISTICS (C_L = 25pF, Input t_r = t_f = 6ns)

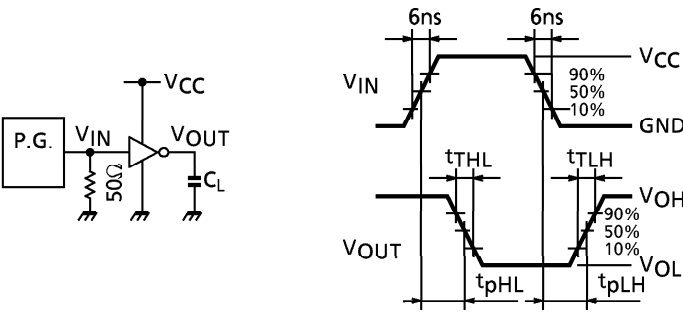
CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	V _{CC}	Ta = 25°C			Ta = -40~85°C		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	t _{TLH} t _{THL}	—	—	1.0	—	70	170	—	240	ns
				1.5	—	25	45	—	55	
				3.0	—	10	15	—	20	
Propagation Delay Time	t _{PLH} t _{PHL}	—	—	1.0	—	70	170	—	210	ns
				1.5	—	25	45	—	55	
				3.0	—	10	15	—	20	
Input Capacitance	C _{IN}	—	—	—	—	5	10	—	10	pF
Power Dissipation Capacitance	C _{PD}	—	Note (1)	—	—	10	—	—	—	

Note (1) : C_{PD} defined as the value of internal equivalent capacitance of IC which is calculated from the operating current consumption without load (refer to Test Circuit).

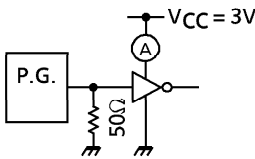
Average operating current can be obtained by the equation as follows.

$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

SWITCHING CHARACTERISTICS TEST CIRCUIT



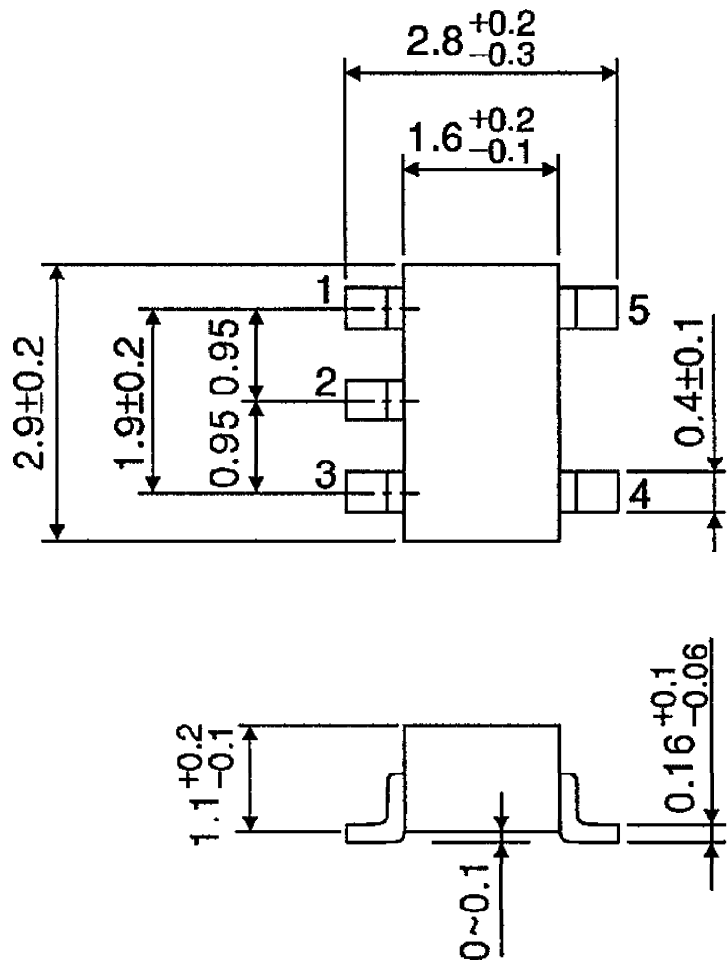
I_{CC (opr)} TEST CIRCUIT



Input waveform is the same as that in case of switching characteristics test.

PACKAGE DIMENSIONS
SSOP5-P-0.95

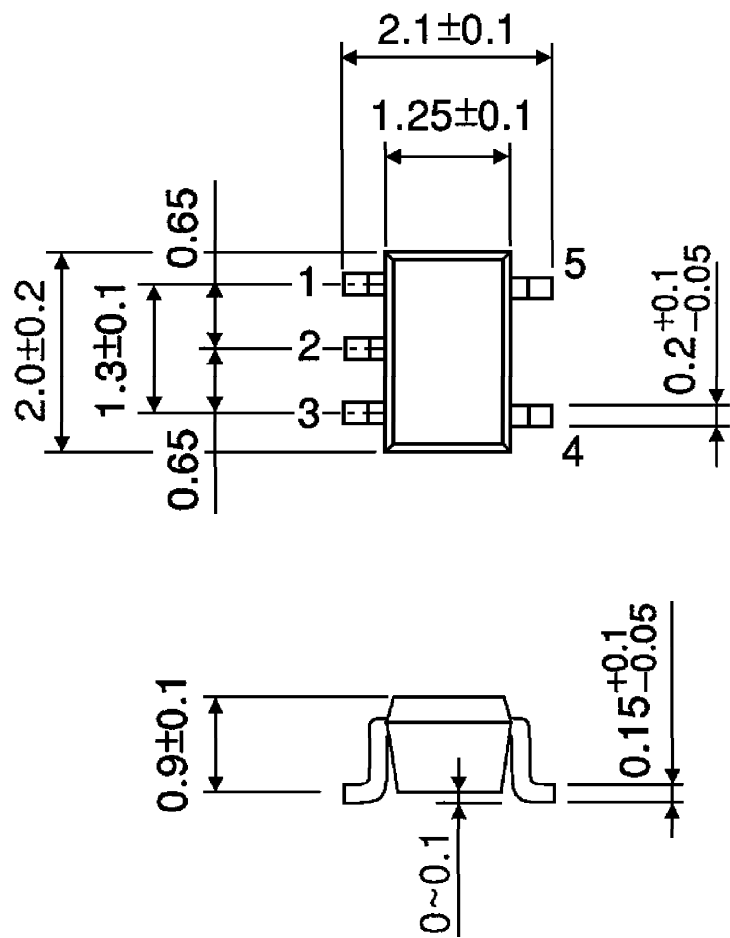
Unit : mm



Weight : 0.016g (Typ.)

PACKAGE DIMENSIONS
SSOP5-P-0.65A

Unit : mm



Weight : 0.006g (Typ.)

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000707EBA

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- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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